Mid-Infrared Raman Sources Using Spontaneous Raman Scattering in Germanium Core Optical Fibers

Pengfei Wang
*Technological University Dublin*, pengfei.wang@tudublin.ie

Christy Charlton O'Mahony
*Dublin City University*

Timothy Lee
*University of Southampton*

See next page for additional authors

Follow this and additional works at: [https://arrow.tudublin.ie/engscheceart](https://arrow.tudublin.ie/engscheceart)

Part of the Engineering Commons

**Recommended Citation**

This Article is brought to you for free and open access by the School of Electrical and Electronic Engineering at ARROW@TU Dublin. It has been accepted for inclusion in Articles by an authorized administrator of ARROW@TU Dublin. For more information, please contact arrow.admin@tudublin.ie, aisling.coyne@tudublin.ie, gerard.connolly@tudublin.ie, vera.kilshaw@tudublin.ie.

Funder: Irish Research Council, Eu Marie-Curie Actions under FP7, Science Foundation Ireland, Royal Society Londong
Mid-infrared Raman sources using spontaneous Raman scattering in germanium core optical fibers

Pengfei Wang, Christy Charlton O'Mahony, Timothy Lee, Rand Ismaeel, Thomas Hawkins et al.

Citation: Appl. Phys. Lett. 102, 011111 (2013); doi: 10.1063/1.4773884
View online: http://dx.doi.org/10.1063/1.4773884
View Table of Contents: http://apl.aip.org/resource/1/APPLAB/v102/i1
Published by the American Institute of Physics.

Related Articles
Restoring transmission of irradiated image fiber bundles

A magnifying fiber element with an array of sub-wavelength Ge/ZnSe pixel waveguides for infrared imaging

Embedded calibration system for the DIII-D Langmuir probe analog fiber optic links

Analytical analysis of modulation instability in fiber optics
AIP Advances 2, 022168 (2012)

Atmospheric pressure dielectric barrier microplasmas inside hollow-core optical fibers

Additional information on Appl. Phys. Lett.
Journal Homepage: http://apl.aip.org/
Journal Information: http://apl.aip.org/about/about_the_journal
Top downloads: http://apl.aip.org/features/most_downloaded
Information for Authors: http://apl.aip.org/authors

ADVERTISEMENTS

AIP | Applied Physics Letters

EXPLORE WHAT’S NEW IN APL
SUBMIT YOUR PAPER NOW!

SURFACES AND INTERFACES
Focusing on physical, chemical, biological, structural, optical, magnetic and electrical properties of surfaces and interfaces, and more...

ENERGY CONVERSION AND STORAGE
Focusing on all aspects of static and dynamic energy conversion, energy storage, photovoltaics, solar fuels, batteries, capacitors, thermoelectrics, and more...
Mid-infrared Raman sources using spontaneous Raman scattering in germanium core optical fibers

Pengfei Wang,1,2,a) Christy Charlton O'Mahony,3 Timothy Lee,1 Rand Ismaeel,1 Thomas Hawkins,4 Yuliya Semenova,2 Lin Bo,2 Qiang Wu,2 Colette McDonagh,3 Gerald Farrell,5 John Ballato,4 and Gilberto Brambilla1
1Optoelectronics Research Centre, University of Southampton, Southampton SO17 1BJ, United Kingdom
2Photonics Research Centre, Dublin Institute of Technology, Kevin Street, Dublin 8, Ireland
3Biomedical Diagnostics Institute, School of Physical Sciences, Dublin City University, Glasnevin, Dublin 9, Ireland
4Center for Optical Materials Science and Engineering Technologies (COMSET), Clemson University, Clemson, South Carolina 29634, USA

(Received 14 September 2012; accepted 17 December 2012; published online 7 January 2013)

Mid-infrared Raman sources based on spontaneous Raman scattering have been demonstrated in a 15-μm diameter glass-clad crystalline germanium optical fiber and in a germanium-wire. A quantum cascade laser was used as pump at a wavelength of 5.62 μm. Because of their ultra-high optical nonlinearities and extremely broad transparency window, germanium core fibers offer the possibility of fabricating compact and efficient mid-infrared sources. © 2013 American Institute of Physics. [http://dx.doi.org/10.1063/1.4773884]

Interest in mid-infrared (IR) light sources has increased in recent years due to their many applications in security, sensing, and the pumping of lasers at even longer wavelengths (terahertz). The most widespread and inexpensive mid-IR sources are thermal emitters, which however suffer from incoherent and low brightness outputs. Indeed, their emissions cannot exceed the radiation power of an ideal black body emitter. While they are suitable for gas detection, they are inappropriate for long-range light detection and ranging (LIDAR), heterodyne measurements, or optical pumping of longer wavelength solid-state lasers, which also require high brightness. Quantum cascade lasers (QCLs) were demonstrated in 1994 (Ref. 1) and are the most promising electrically pumped semiconductor lasers for mid- and far-IR light generation. While QCLs can generate narrowband and high quality continuous wave (CW) and pulsed beams, they are narrowband, relatively inefficient,2,3 often require low temperature operation, and are available only at selected wavelengths. Active fibers have been proposed as a means to achieve efficient lasing in the mid-IR, but to date, such fibers rely on compound glasses, such as chalcogenides,4 which are transparent in the mid-IR but are not easily available and generally mechanically fragile. Finally parametric processes,5 for example, in an optical parametric oscillator, have been widely used, but these require a nonlinear medium (usually crystals) and multiple high peak power pumps.

There is thus a need to develop efficient high brightness sources at long wavelengths, without the disadvantages associated with existing sources. In this letter, Raman scattering is exploited in order to generate light in the mid-infrared region (at λ > 6 μm) using a germanium wire and a glass-clad germanium core optical fiber.

Germanium (Ge) has a large n2 nonlinearity (∼103 times that of silica6,7), a high optical damage threshold compared with traditional nonlinear glasses,8 and, most importantly, an extremely broad transparency window that extends from the near-infrared well into the mid-infrared (λ = 2–20 μm) spectral regions.9 Ge-based passive optical components such as mirrors and lenses have found numerous applications in IR imaging systems operating in the atmospheric windows (both 3–5 and 8–13 μm), where natural greenhouse gases do not exhibit strong absorption. Some active components have been demonstrated in the near-IR wavelengths such as an electrically pumped Ge laser operating between 1520 nm and 1700 nm (Ref. 10) and resonance modes observed over the range of 1500–1675 nm from a resonator fabricated by integrating a Ge light emitting diode with a microdisk cavity.11 However, Ge in the near-IR has strong absorption, which reduces propagation length and conversion efficiency in nonlinear processes. On the other hand, for λ > 1.9 μm, Ge absorption becomes negligible for propagation lengths of the order of centimeters and, for example, whispering gallery modes have recently been observed around λ ~ 2 μm.13 Two-photon absorption also becomes negligible at λ > 4 μm. In the past, Raman scattering has been used to characterize semiconductor materials15 and, recently, to generate the wavelengths in the near-IR region.10,14 Here, we exploit Raman scattering to generate high output power fiber-based sources in the mid-IR.

The fiber sample employed here was manufactured at Clemson University (Clemson, USA) and has a crystalline Ge core and an amorphous borosilicate cladding with diameters of 15 μm (core) and 150 μm (total fiber diameter), respectively.15 A microscope image of the fiber is shown in Fig. 1(a). The fiber had a refractive index difference of Δn = 2.5 and supported multimode operation in the wavelength range λ < 10 μm. Figs. 1(b) and 1(c) present simulated HE11 modal intensity profiles at the pump and at the borosilicate Raman scattering wavelengths, respectively. When light is launched into the fundamental mode, most of the intensity is confined to the core. The fraction of power, η, propagating...
in the core was calculated to be $g = 0.999905$ at $k = 5.62 \text{ lm}$ and $g = 0.999774$ at $k = 7.60 \text{ lm}$, calculated from the Poynting vector $S$ using the equation of $g = \frac{\int \text{core} S dA}{\int S dA}$.

Fig. 2 shows the optical set-up employed. A distributed feedback (DFB) QCL (Alpes Lasers, Neuchatel, Switzerland) system equipped with a temperature controller (Alpes Lasers, TC-51), modulated by a QCL pulse switching and timing module (Alpes Lasers, TPG 128), was operated at a temperature of 12°C and modulated at a pulse duration up to 10 ns with a period of 2.5 μs. The pulse amplitude was controlled by an external power supply set up to 16.5 V. Light at $\lambda \sim 5.62 \mu m$ was launched from the QCL into the Ge fiber with a length of 4 mm via a collimator, an infrared polarizer, and a ZnSe lens. Light emitted from the distant end of the Ge fiber was collected by a Fourier transform infrared spectrometer (FTIR, Thermo Fisher Scientific, USA) connected to a personal computer (PC).

Fig. 3 shows the Raman spectrum collected at the Ge fiber output. In analyzing the Raman spectroscopy, two major features can be identified at about 300 and 400–600 cm$^{-1}$. The Raman peak located at $\sim 300 \text{ cm}^{-1}$ can be attributed to crystalline Ge. The broader peak at longer wavenumbers (400–800 cm$^{-1}$) can be attributed to the borosilicate cladding. The bands at 600–800 cm$^{-1}$ are due to stretching vibrations of terminal groups of silicon-oxygen tetrahedrons with a different ratio of bridging and nonbridging oxygen atoms, while the 530–570 cm$^{-1}$ band in the low-wavenumber region, which is the dominant feature in borosilicate glasses, is primarily due to symmetrical stretching and to a lesser extent to deformation vibrations of Si–O–Si bridges. Although a peak around 520 cm$^{-1}$ might indicate that crystalline silicon could have separated during the fabrication of the Ge-core fiber at a high temperature, the recorded spectrum has a broader feature, consistent with a borosilicate glass. The broadening and asymmetry of the narrow Raman peaks, when compared to the reference spectra presented in Ref. 16, can be attributed to the relatively low resolution ($\sim 3 \text{ cm}^{-1}$) of the instrument used and possibly to the known polycrystallinity of Ge in the core of the optical fiber.

In order to verify that the Raman scattering in the region 400–1000 cm$^{-1}$ is indeed due to the borosilicate cladding, the Ge-core/borosilicate-glass-cladding fiber was immersed in a 48% hydrofluoric acid (HF) for 7 min to remove the cladding and then rinsed in deionized water to remove any residual HF. As shown in the inset of Fig. 4, the etching process provides a Ge wire with a 15 μm diameter. Fig. 4 also shows the Raman spectrum collected from the Ge wire output for an average input power from the QCL of $\sim 8 \text{ mW}$; only the typical Ge Raman shift at $\sim 300 \text{ cm}^{-1}$ is observed, in contrast to the broadband nature of Fig. 3, confirming that the Raman scattering in the region 400–1000 cm$^{-1}$ in the fiber is due to the borosilicate cladding.

Fig. 5 shows the Raman signal for a low and a high average powers of $\sim 20 \mu W$ and 8 mW, respectively, from the Ge

![FIG. 1. (a) Optical micrograph of the glass-clad crystalline Ge core fiber and intensity profiles of the fundamental HE$_{11}$ mode at (b) $\lambda = 5.62 \mu m$ and (c) $\lambda = 7.60 \mu m$.](image)

![FIG. 2. Diagram of the experimental set-up for Raman scattering measurements.](image)

![FIG. 3. Raman spectrum of Ge fiber recorded with $20 \mu W$ average pump power.](image)
The Raman gain coefficient for Ge is estimated to be $g_r = \frac{8\pi c^2 \rho}{6\hbar n^2} \frac{d\sigma}{d\omega} d\Omega$,

$$g_s = \frac{8\pi^2 \omega_p \rho}{\hbar n^2} \frac{d\sigma}{d\omega} d\Omega,$$

where $c$ is the speed of light in vacuum, $\rho$ is the scatterer density, $\hbar$ is the reduced Planck’s constant, $\omega_p$ and $\omega_s$ are the pump and Raman frequency, $n(\omega_s)$ is the refractive index of the scattering medium at the Raman frequency, and $\Delta\omega$ is the FWHM of the spontaneous Raman line-shape. From Eq. (1), the Raman gain coefficient for Ge is estimated to be $g_s \approx 8.6 \times 10^{-12}$ m/W.

Comparing the estimated Raman gain coefficient for Ge with published values is difficult because no data are available in the literature for the spontaneous cross section of germanium. However, it was found in Ref. 13 that $d\sigma/d\Omega|_{Ge}$ is 1.25–2 times larger than $d\sigma/d\Omega|_{Si}$ at $\lambda \approx 1.6 \mu m$, which is 2.3 \times 10^{13} times larger than that of a standard SMF28 silica fiber. As $\Delta\omega_{Si} \approx 1.2 \Delta\omega_{Ge}$ (Ref. 13) and Eq. (1) is dependent on $\omega_s^{-3}$, assuming $n_{Ge} \approx 4.02$, $n_{Si} \approx 3.42$, and $d\sigma/d\Omega|_{Ge} = 2 d\sigma/d\Omega|_{Si}$, then the stimulated gain coefficient for Ge at $\lambda \approx 5.6 \mu m$ based on the available data in the literature can be determined as $g_s(Ge) \approx 3.05 \times 10^{-12}$ m/W, comparable with the estimated value above. Work is presently underway to increase the power coupling between the source and the Ge fiber and thus improve the pumping efficiency of the system.

In conclusion, mid-IR sources that exploit the spontaneous Raman scattering in semiconductor core optical fibers have been demonstrated. Specifically, strong and broadband spectra were observed from a 15 $\mu$m core size glass-clad germanium core fiber with a length of 4 mm and a germanium wire pumped by a QCL source at 5.62 $\mu$m. Although the QCL pumping source used in the experiments is not low cost, nevertheless the system provides enhanced power output and the pumping efficiency of the system can be enhanced by optimizing both the pumping source and the coupling method. Finally, it is important to point out that this work opens an approach to generate high brightness mid-IR radiation using a Ge fiber. Similarly to the case of high power fiber lasers, low brightness sources can be used to pump fiberized components to produce a high brightness output. This technology can expand the usages of silicon/germanium photonics beyond data communication and into the applications of trace gas sensing, biomedical, and military systems.

The authors would like to thank Dr. X. Feng and Professor J. Zheng for the helpful discussions. P. Wang was funded by the Irish Research Council, co-funded by the EU Marie-Curie Actions under FP7, Q. Wu gratefully acknowledges the support of Science Foundation Ireland under Grant Nos. 07/ENG/11200, 11/TIDA/B2051, 07/ENG/11200-STTF11, and 07/ENG/11200-ISTTF11, and G. Brambilla gratefully acknowledges the Royal Society (London) for his research fellowship.